



DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C			
00)/	$23m\Omega$ @ $V_{GS} = 4.5V$	5.2A			
20V	$27m\Omega @ V_{GS} = 2.5V$	4.8A			

Features and Benefits

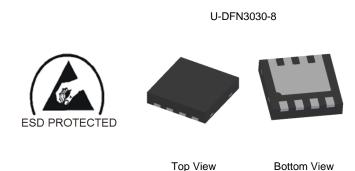
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

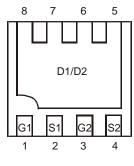
Description and Applications

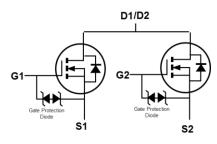
This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

Mechanical Data

- Case: U-DFN3030-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208@4
- Polarity: See Diagram
- Weight: 0.0172 grams (Approximate)







Bottom View Pin Configuration

Equivalent Circuit

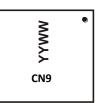
Ordering Information (Note 4)

- 7			
	Part Number	Case	Packaging
DMN2024UDH-7 U-0		U-DFN3030-8	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



CN9 = Product Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 for 2018) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V_{GSS}	±10	V
Continuous Drain Current (Note 5) Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$		I _D	5.2 4.2	А	
Pulsed Drain Current			I _{DM}	45	А
Avalanche Current (Note 7) L = 0.1mH			I _{AS}	12	Α
Avalanche Energy (Note 7) L = 0.1mH			E _{AS}	8	mJ

Thermal Characteristics

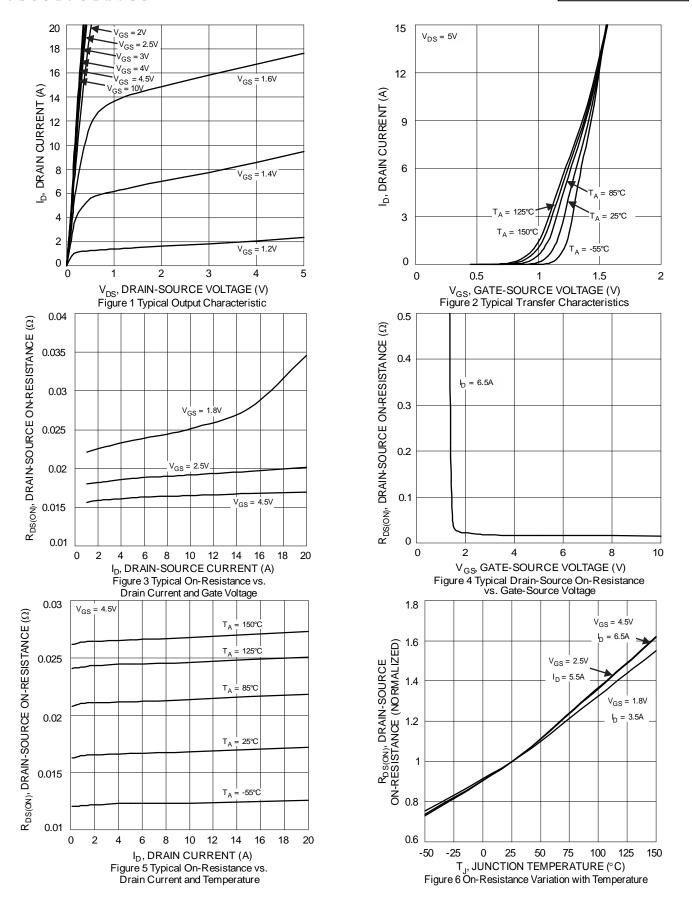
Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	P_{D}	0.95	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	132	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.76	W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	71	°C/W	
Thermal Resistance, Junction to Case (Note 6)	Steady State	$R_{\theta JC}$	14	-C/VV
Operating and Storage Temperature Range	·	$T_{J,}T_{STG}$	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

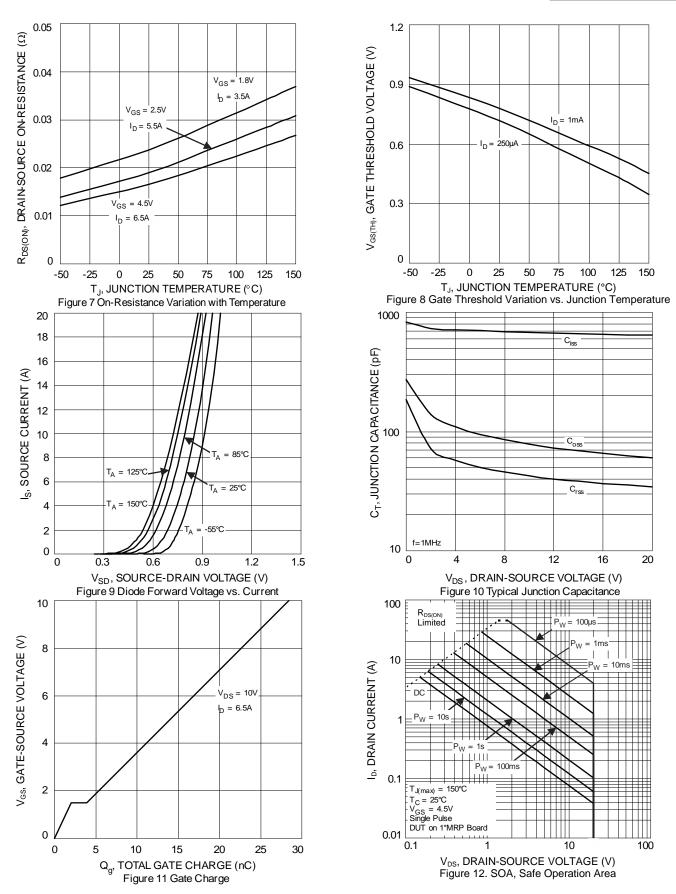
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	1	1.0	μΑ	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 8V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	0.35	1	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
		_	16	23		$V_{GS} = 4.5V, I_D = 6.5A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	19	27	mΩ	$V_{GS} = 2.5V, I_D = 5.5A$	
		_	24	34		$V_{GS} = 1.8V, I_D = 3.5A$	
Diode Forward Voltage	V_{SD}	_	0.65	1.0	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{iss}		647	_	pF	101/1/	
Output Capacitance	Coss	1	78		pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	38	_	pF		
Gate Resistance	R_g	_	628	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	7.1	_	nC	15)/)/ 40)/	
Gate-Source Charge	Q_{gs}	_	0.9	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$	
Gate-Drain Charge	Q _{qd}	_	0.7	_	nC	$I_D = 6.5A$	
Turn-On Delay Time	t _{D(ON)}	_	98	_	ns		
Turn-On Rise Time	t _R	_	140	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$ $R_{L} = 10\Omega, R_{G} = 6\Omega$	
Turn-Off Delay Time	t _{D(OFF)}	_	1024	_	ns		
Turn-Off Fall Time	t _F	_	434	_	ns		
Reverse Recovery Time	t _{RR}	_	245	_	ns	1 44 4:/44 4004/:	
Reverse Recovery Charge	Q _{RR}	_	149	_	nC	I _F = 1A, di/dt = 100A/μs	

- Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PCB, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.

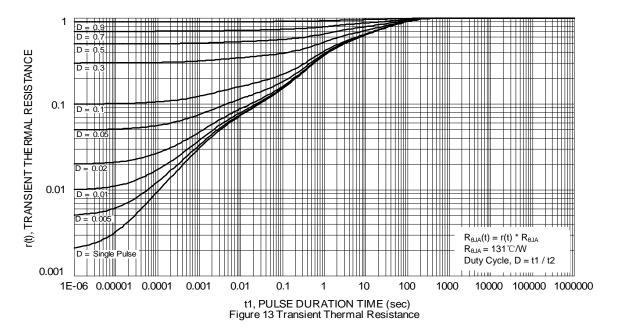










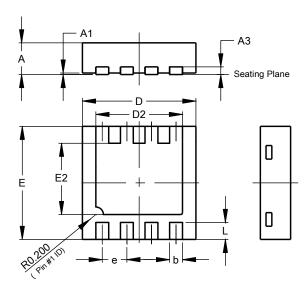




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN3030-8

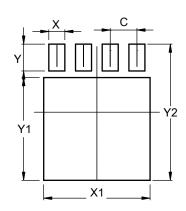


U-DFN3030-8						
Dim Min		Max	Тур			
Α	0.57	0.63	0.60			
A1	0	0.05	0.02			
A3	-	-	0.15			
b	0.29	0.39	0.34			
D	2.90	3.10	3.00			
D2	2.19	2.39	2.29			
е	-	-	0.65			
Е	2.90	3.10	3.00			
E2	1.64	1.84	1.74			
Ĺ	0.30	0.60	0.45			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN3030-8



Dimensions	Value		
Dillielisions	(in mm)		
С	0.650		
Х	0.390		
X1	2.590		
Y	0.650		
Y1	2.490		
Y2	3.300		



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